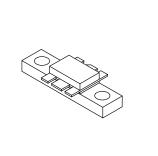
The RF Line **RF Power Transistor**

The TP3008 is designed for 960 MHz cellular radio base stations in both analog and digital applications. It incorporates high value emitter ballast resistors, gold metallizations and offers a high degree of reliability and ruggedness.

- Specified 24 Volts, 960 MHz Characteristics Output Power — 4 Watts Gain — 11.5 dB min Efficiency — 45% min
- Class AB Operation
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCER	40	Vdc
Collector-Base Voltage	VCBO	50	Vdc
Emitter-Base Voltage	VEBO	4	Vdc
Collector-Current - Continuous	IC	1	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	35 0.2	Watts W/°C
Storage Temperature Range	T _{stg}	- 65 to +150	°C
Operating Junction Temperature	ТJ	200	°C



TP3008

4 W, 960 MHz RF POWER TRANSISTOR

NPN SILICON

CASE 319-07, STYLE 2

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case		5	°C/W

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted.)

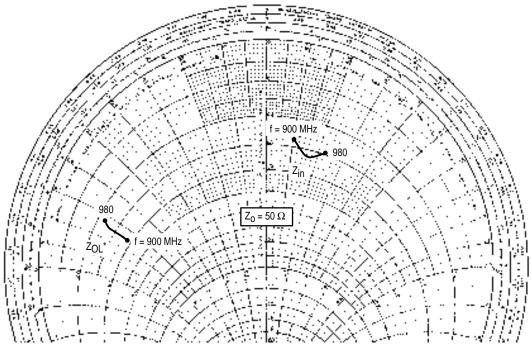
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I _C = 15 mA, R _{BE} = 75 Ω)	V(BR)CER	40	—	_	Vdc
Collector–Emitter Breakdown Voltage (I _C = 3 mAdc)	V _(BR) CBO	45	_	_	Vdc
Emitter–Base Breakdown Voltage $(I_E = 2 \text{ mA}, I_C = 0)$	V _{(BR)EBO}	3.5	_	—	Vdc
Collector–Emitter Leakage ($V_{CE} = 26 \text{ V}, \text{R}_{BE} = 75 \Omega$)	ICER	_	_	2	mA
ON CHARACTERISTICS					
DC Current Gain (I _C = 0.2 Adc, V_{CE} = 5 Vdc)	hFE	15	_	120	—
DYNAMIC CHARACTERISTICS					
Output Capacitance $(V_{CE} = 24 \text{ V}, I_E = 0, f = 1 \text{ MHz})$	C _{ob}	_	6	—	pF

(continued)



ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
FUNCTIONAL TESTS (V _{CC} = 24 V, f = 960 MHz)					
Common–Emitter Amplifier Gain (P _{out} = 4 W, I _{CQ} = 50 mA)	Gp	11.5	_	—	dB
Collector Efficiency (P _{out} = 4 W, I _{CQ} = 50 mA)	h	45	50	—	%
Load Mismatch (P _{out} = 4 W, I _{CQ} = 50 mA, Load VSWR = 5:1, all phase angles at frequency of test)	Ψ	No Degradation in Output Power			

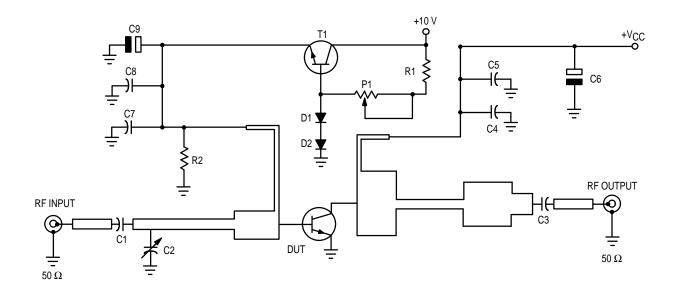


Output impedance with circuit tuned for maximum gain @ P_{OUt} = 4 W, $~V_{CE}$ = 24 V

f (MHz)	Z _{in} (Ω)	Z _{OL} * (Ω)
900	6 + j5	7.6 – j15
935	6.2 + j4.7	5.5 – j13.5
960	6.8 + j3.6	5.5 – j13.5
980	7.2 + j2	5.3 – j13.5

Z_{OL}* = Conjugate of optimum load impedance into which the device operates at a given output power, voltage, current and frequency.

Figure 1. Series Equivalent Input and Output Impedance



Components List

C1,C3	100 pF, ATC Chip Capacitor 100A	D1,D2	Diode, BAS16
C2	1 to 5 pF, Trimmer Capacitor	P1	1 kΩ, Trimmer
C4,C7	330 pF, Chip Capacitor 0805	R1	1 kΩ, Resistor
C5,C8	10 nF, Chip Capacitor 0805	R2	56 Ω, 0805 Resistor
C6	15 μF, 63 V, Capacitor	T1	Transistor, NPN Type, MJD31C
C9	100 μF, 16 V, Capacitor		

Figure 2. 960 MHz Electrical Schematic

TYPICAL CHARACTERISTICS

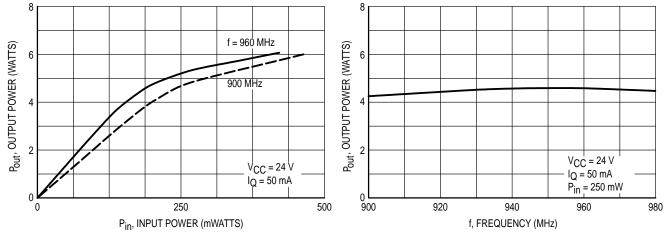




Figure 4. Output Power versus Frequency

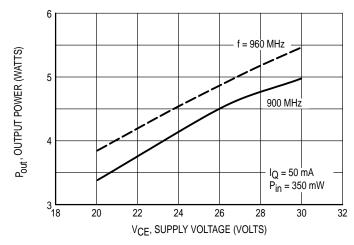
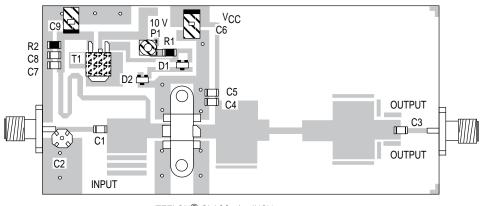


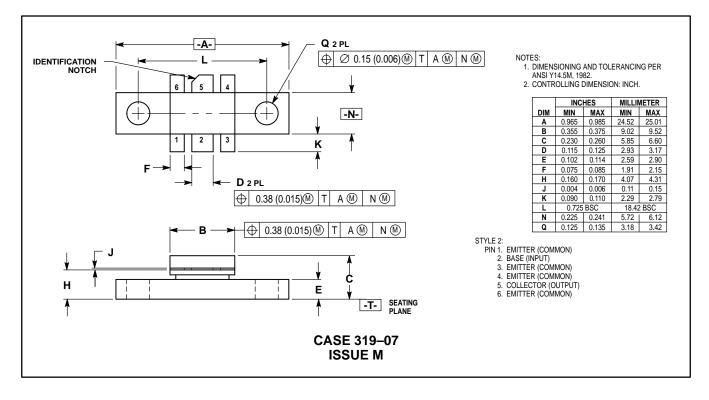
Figure 5. Output Power versus Supply Voltage



 $\text{TEFLON}^{(\!R\!)}$ GLASS 1/50 INCH ϵ_{f} = 2.55

Figure 6. 960 MHz Test Circuit Components View

PACKAGE DIMENSIONS



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